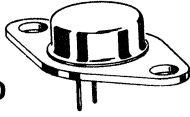


2N4898 thru 2N4900 (SILICON)

CASE 80
(TO-66)



Medium-power PNP silicon transistors designed for driver circuits, switching, and amplifier applications. Complement to NPN 2N4910 thru 2N4912.

Collector connected to case

MAXIMUM RATINGS

Rating	Symbol	2N4898	2N4899	2N4900	Unit
Collector-Emitter Voltage	V_{CEO}	40	60	80	Vdc
Collector-Base Voltage	V_{CB}	40	60	80	Vdc
Emitter-Base Voltage	V_{EB}	← 5.0 →			Vdc
Collector Current – Continuous *	I_C^*	← 1.0 →			Adc
		← 4.0 →			
Base Current	I_B	← 1.0 →			Adc
Total Device Dissipation $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	← 25 →			Watts
		← 0.143 →			W/ $^\circ\text{C}$
Operating & Storage Junction Temperature Range	T_J, T_{stg}	← -65 to +200 →			$^\circ\text{C}$

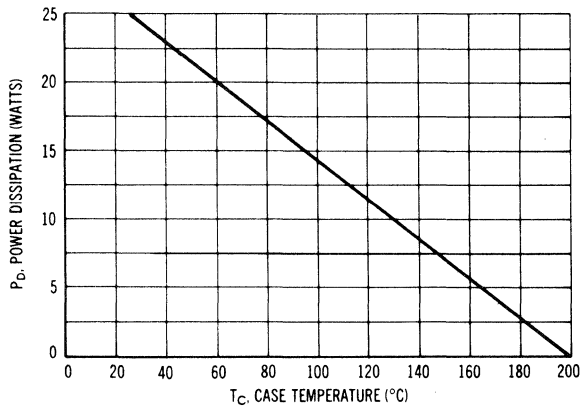
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	7.0	$^\circ\text{C}/\text{W}$

* The 1.0 Amp maximum I_C value is based upon JEDEC current gain requirements.

The 4.0 Amp maximum value is based upon actual current-handling capability of the device (see Figure 5).

FIGURE 1 – POWER-TEMPERATURE DERATING CURVE



2N4898 thru 2N4900 (continued)

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Fig. No.	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage ⁽¹⁾ (I _C = 0.1 Adc, I _B = 0) 2N4898 2N4899 2N4900	-	BV _{CEO(sus)}	40 60 80	- - -	Vdc
Collector Cutoff Current (V _{CE} = 20 Vdc, I _B = 0) (V _{CE} = 30 Vdc, I _B = 0) (V _{CE} = 40 Vdc, I _B = 0)		I _{CEO}	- - -	0.5 0.5 0.5	mAdc
Collector Cutoff Current (V _{CE} = Rated V _{CEO} , V _{BE(off)} = 1.5 Vdc) (V _{CE} = Rated V _{CEO} , V _{BE(off)} = 1.5 Vdc, T _C = 150°C)	12	I _{CEX}	- -	0.1 1.0	mAdc
Collector Cutoff Current (V _{CB} = Rated V _{CB} , I _E = 0)	-	I _{CBO}	-	0.1	mAdc
Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	-	I _{EBO}	-	1.0	mAdc

ON CHARACTERISTICS ⁽¹⁾

DC Current Gain (I _C = 50 mAdc, V _{CE} = 1.0 Vdc) (I _C = 500 mAdc, V _{CE} = 1.0 Vdc) (I _C = 1.0 Adc, V _{CE} = 1.0 Vdc)	8	h _{FE}	40 20 10	- 100 -	-
Collector-Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 0.1 Adc)	9 11 13	V _{CE(sat)}	-	0.6	Vdc
Base-Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 0.1 Adc)	11 13	V _{BE(sat)}	-	1.3	Vdc
Base-Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 1.0 Vdc)	11 13	V _{BE(on)}	-	1.3	Vdc

SMALL SIGNAL CHARACTERISTICS

Current-Gain-Bandwidth Product (I _C = 250 mAdc, V _{CE} = 10 Vdc, f = 1.0 MHz)	-	f _T	3.0	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 100 kHz)	-	C _{ob}	-	100	pF
Small-Signal Current Gain (I _C = 250 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	-	h _{fe}	25	-	-

⁽¹⁾ Pulse Test: PW ≈ 300 μs, Duty Cycle ≈ 2.0%

FIGURE 2 — SWITCHING TIME EQUIVALENT CIRCUIT

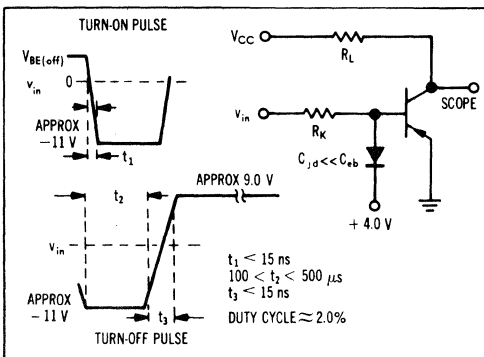
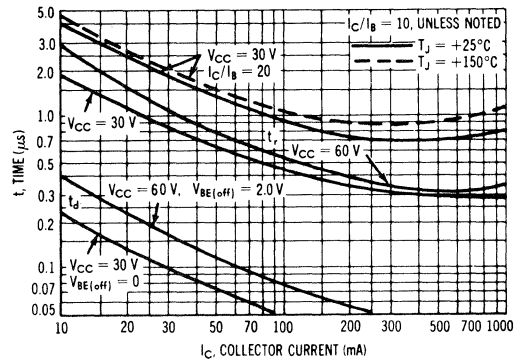


FIGURE 3 — TURN-ON TIME



2N4898 thru 2N4900 (continued)

FIGURE 4 — THERMAL RESPONSE

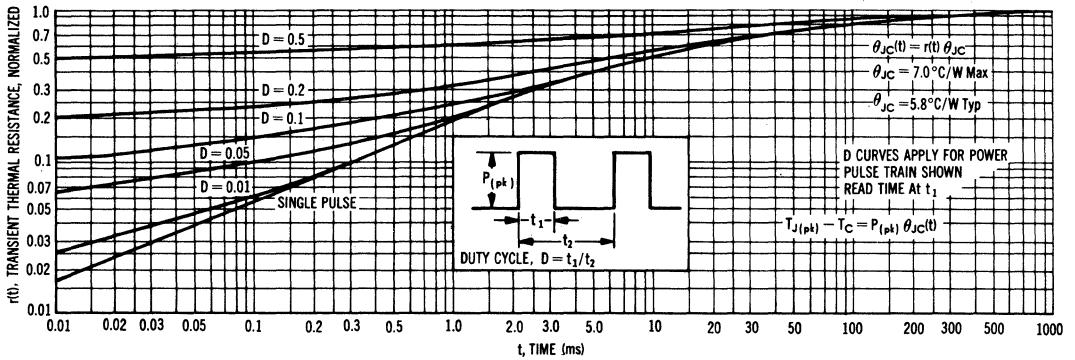
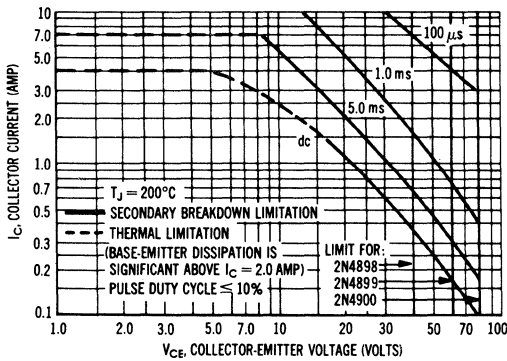


FIGURE 5 — ACTIVE-REGION SAFE OPERATING AREA



The safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor which must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 5 is based upon $T_{J(pk)} = 200^\circ\text{C}$; T_C is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 200^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power which can be handled to values less than the limitations imposed by secondary breakdown.

FIGURE 6 — STORAGE TIME

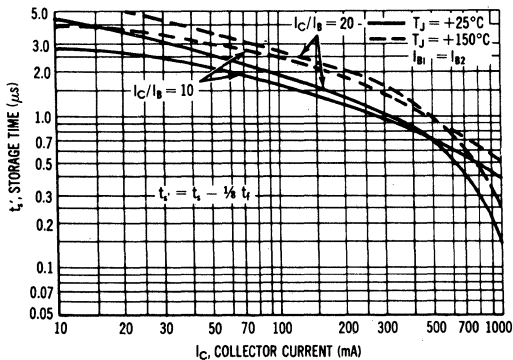
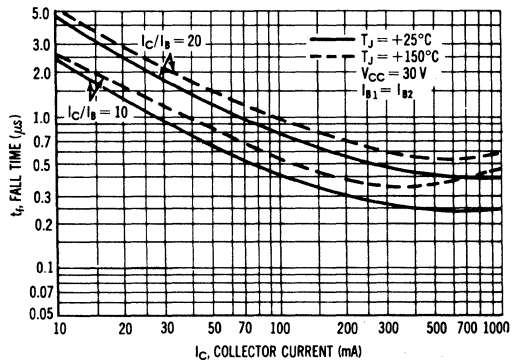


FIGURE 7 — FALL TIME



2N4898 thru 2N4900 (continued)

FIGURE 8 — CURRENT GAIN

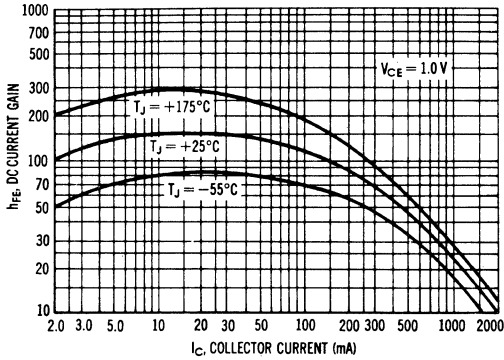


FIGURE 9 — COLLECTOR SATURATION REGION

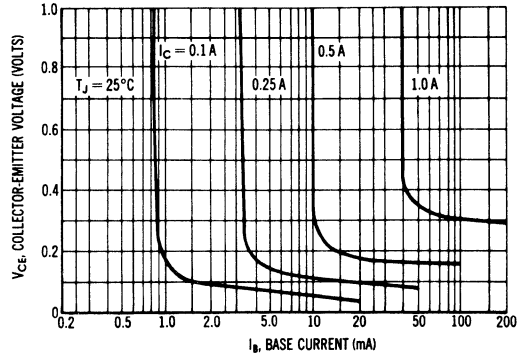


FIGURE 10 — EFFECTS OF BASE-EMITTER RESISTANCE

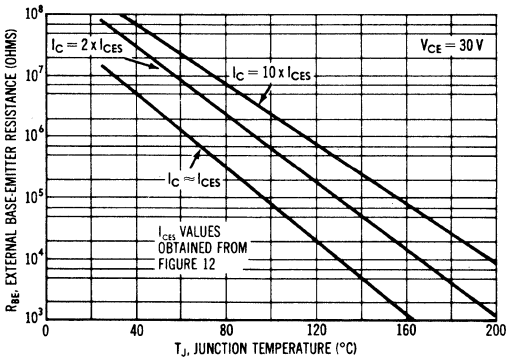


FIGURE 11 — "ON" VOLTAGE

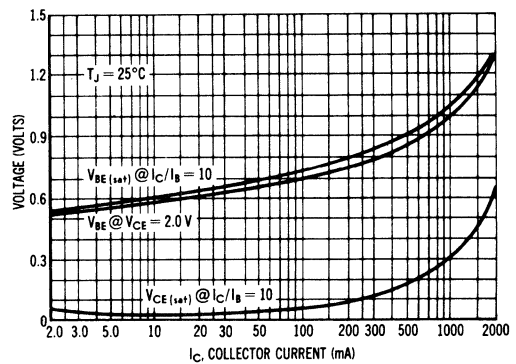


FIGURE 12 — COLLECTOR CUTOFF REGION

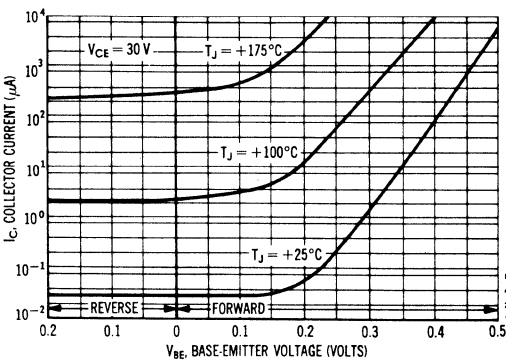


FIGURE 13 — TEMPERATURE COEFFICIENTS

